Diode Semiconductor Device - Page 1 of 1



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| | closure Material: |
|-----|---|
| Gla | ass |
| Ov | erall Length: |
| 0.2 | 200 inches |
| Те | rminal Length: |
| 0.5 | i00 inches |
| Ov | erall Diameter: |
| 0.0 | 990 inches |
| Jo | int Electronic Device Engineering Council/jedec/case Outline Designation: |
| Do | -35 |
| Мс | ounting Method: |
| Те | rminal |
| Fe | atures Provided: |
| He | rmetically sealed case |
| Se | miconductor Material: |
| Sil | icon |
| Vo | Itage Rating In Volts Per Characteristic: |
| 6.2 | 2 regulator voltage |
| Vo | Itage Tolerance In Percent: |
| -5. | 0/+5.0 |
| Cu | rrent Rating Per Characteristic: |
| 5.0 | 0 milliamperes source cutoff current horsepower metric |
| Ро | wer Rating Per Characteristic: |
| 0.4 | 0 watts small-signal input power, common-collector preset |
| Ма | iximum Operating Tempurature Per Measurement Point: |
| 17 | 5.0 degrees celsius junction |
| Те | rminal Type And Quantity: |
| 2ι | ininsulated wire lead |
| Sh | elf Life: |
| N/a | a |
| Un | it Of Measure: |
| | |
| De | militarization: |
| No | |
| Fii | g: |
| | 10a0 |